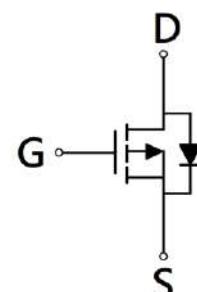
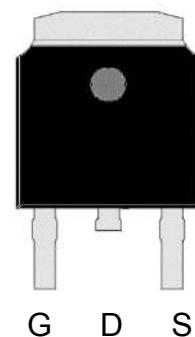


P-Channel Enhancement Mode Power MOSFET

Features:

- Low Gate Charge
- Fast Switching Characteristic

TO-252



G : Gate S : Source D : Drain

BV _{DSS}	-100V
I _D @V _{GS} =-10V, T _c =25°C	-8A
I _D @V _{GS} =-10V, T _A =25°C	-2.6A
R _{D(S)} (ON) typ. @ V _{GS} =-10V, I _D =-3A	195mΩ
R _{D(S)} (ON) typ. @ V _{GS} =-4.5V, I _D =-3A	210mΩ

Ordering Information

Device	Package	Shipping
KJB190P10	TO-252 (Pb-free lead plating and halogen-free package)	2500 pcs / Tape & Reel

Absolute Maximum Ratings ($T_A=25^\circ C$)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V_{DS}	-100	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current @ $V_{GS}=-10V$, $T_c=25^\circ C$	I_D	-8	A
Continuous Drain Current @ $V_{GS}=-10V$, $T_c=100^\circ C$		-5	
Continuous Drain Current @ $V_{GS}=-10V$, $T_A=25^\circ C$		-2.6	
Continuous Drain Current @ $V_{GS}=-10V$, $T_A=70^\circ C$		-2	
Pulsed Drain Current	I_{DM}	-24	
Continuous Body Diode Forward Current @ $T_c=25^\circ C$	I_S	-8	
Pulsed Body Diode Forward Current @ $T_c=25^\circ C$	I_{SM}	-24	
Avalanche Current @ $L=0.1mH$	I_{AS}	-12	
Avalanche Energy @ $L=0.5mH$	E_{AS}	9	mJ
Total Power Dissipation	$T_c=25^\circ C$	*a 31	W
	$T_c=100^\circ C$	*a 12	
	$T_A=25^\circ C$	*b 3	
	$T_A=70^\circ C$	*b 1.9	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	°C

Thermal Data

Parameter	Symbol	Steady State	Unit
Thermal Resistance, Junction-to-case	$R_{\theta JC}$	4	°C/W
Thermal Resistance, Junction-to-ambient	$R_{\theta JA}$	42	

Note:

- *a. The power dissipation P_D is based on $T_{J(MAX)}=150^\circ C$, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
- *b. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR-4 board with 2 oz. copper, in a still air environment with $T_A=25^\circ C$. The power dissipation P_D is based on $R_{\theta JA}$ and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- *c. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ C$. Ratings are based on low frequency and low duty cycles to keep initial $T_J=25^\circ C$.

Electrical Characteristics ($T_A=25^\circ\text{C}$, unless otherwise specified)

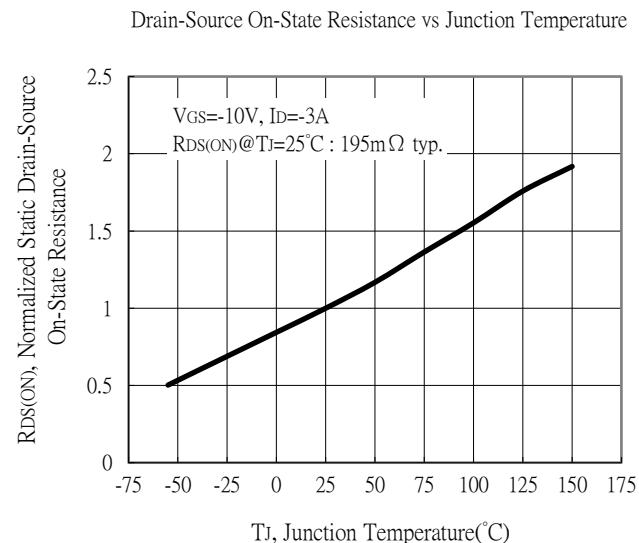
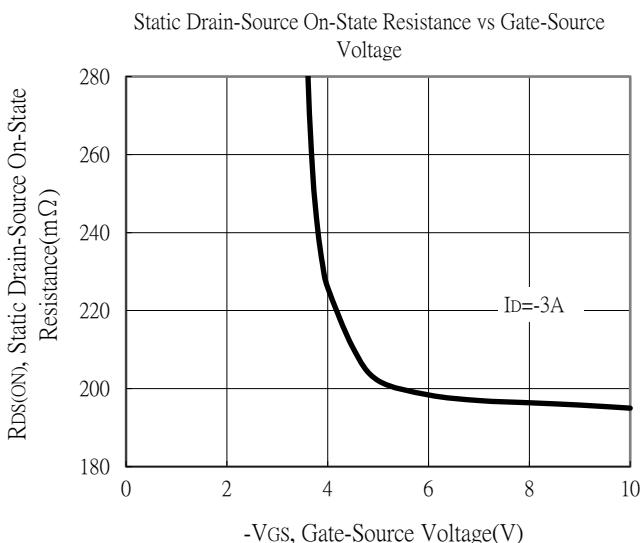
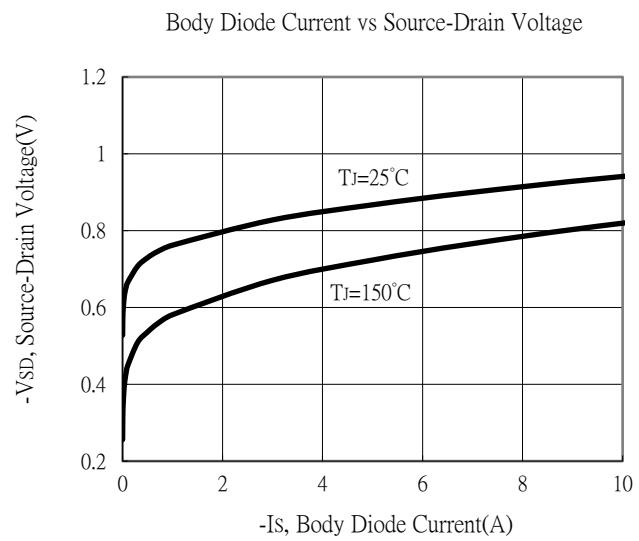
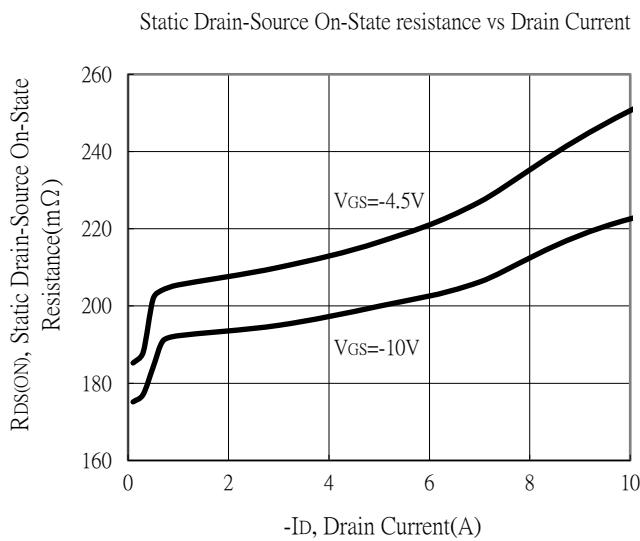
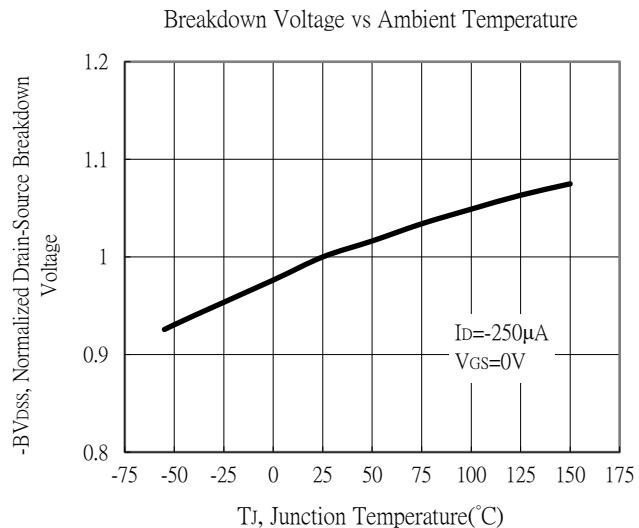
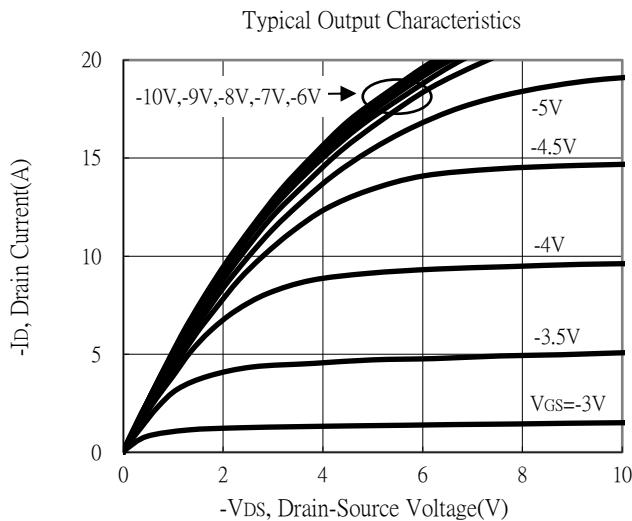
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	-100	-	-	V	V _{GS} =0V, I _D =-250μA
V _{GS(th)}	-1	-	-2.5		V _{DS} =V _{GS} , I _D =-250μA
G _{FS}	-	7.8	-	S	V _{DS} =-5V, I _D =-3A
I _{GSS}	-	-	±100	nA	V _{GS} =±20V, V _{DS} =0V
I _{DSS}	-	-	-1	μA	V _{DS} =-80V, V _{GS} =0V
R _{D(S(ON))}	-	195	240	mΩ	V _{GS} =-10V, I _D =-3A
	-	210	295		V _{GS} =-4.5V, I _D =-3A
Dynamic					
C _{iss}	-	740	-	pF	V _{DS} =-50V, V _{GS} =0V, f=1MHz
C _{oss}	-	40	-		
C _{rss}	-	32	-	nC	f=1MHz
R _g	-	4.7	-		
Q _g *1, 2	-	7.5	-		V _{DS} =-50V, I _D =-3A, V _{GS} =-4.5V
Q _g *1, 2	-	15	-		
Q _{gs} *1, 2	-	2.8	-	ns	V _{DS} =-50V, I _D =-3A, V _{GS} =-10V
Q _{gd} *1, 2	-	3.7	-		
t _{d(ON)} *1, 2	-	11	-		
t _r *1, 2	-	2	-		
t _{d(OFF)} *1, 2	-	41	-	ns	V _{DS} =-50V, I _D =-1A, V _{GS} =-10V, R _{GS} =6Ω
t _f *1, 2	-	3.8	-		
Source-Drain Diode					
V _{SD} *1	-	-0.83	-1.2	V	I _S =-3A, V _{GS} =0V
t _{rr}	-	21	-	ns	I _F =-3A, dI _F /dt=100A/μs
Q _{rr}	-	25	-		

Note:

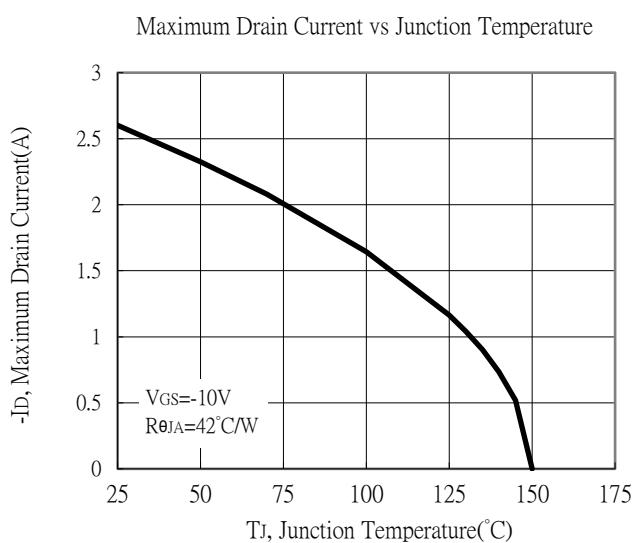
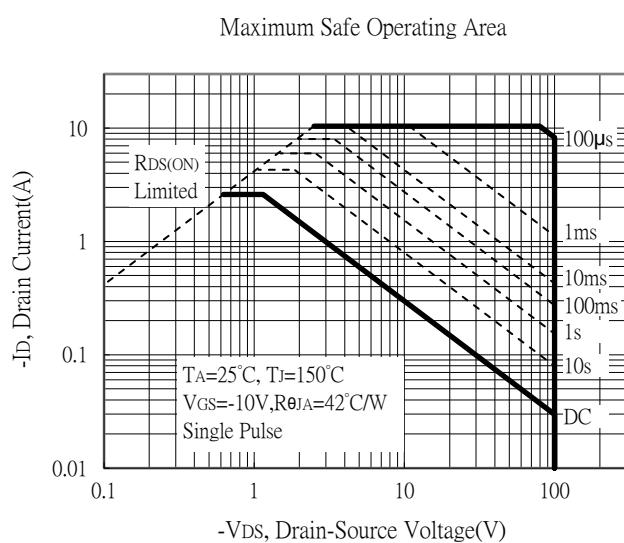
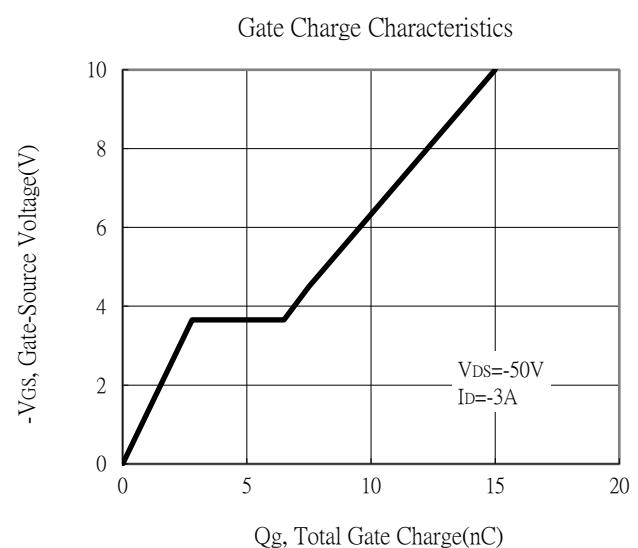
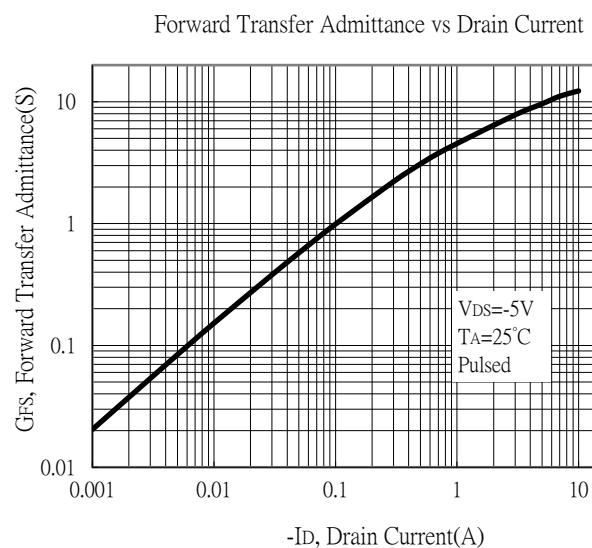
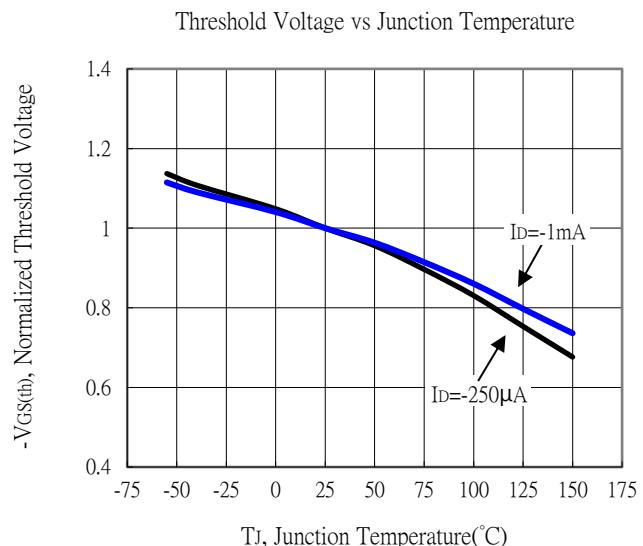
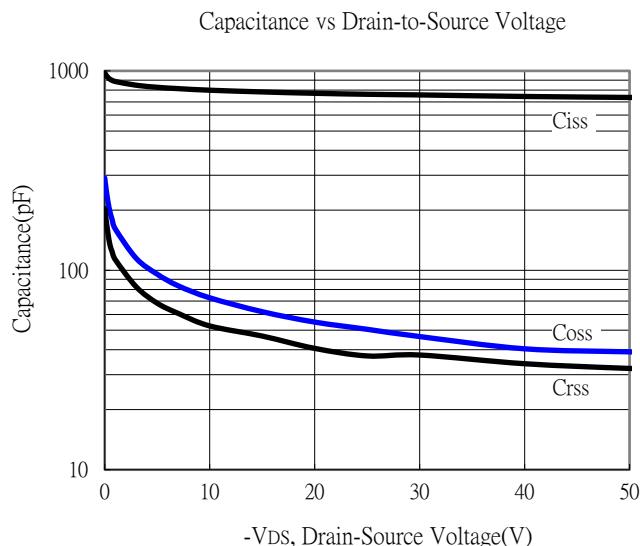
*1. Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

*2. Independent of operating temperature

Typical Characteristics

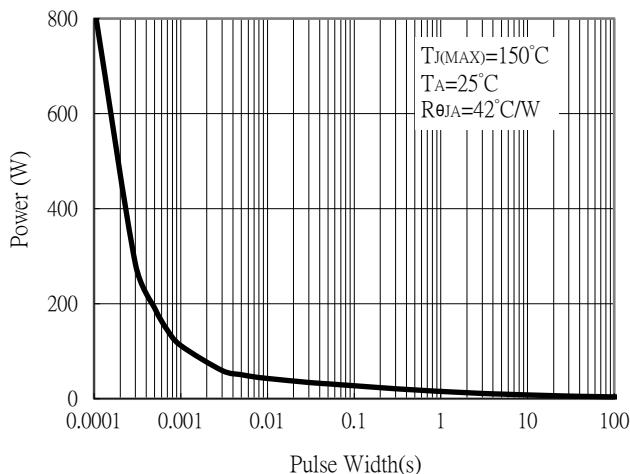


Typical Characteristics (Cont.)

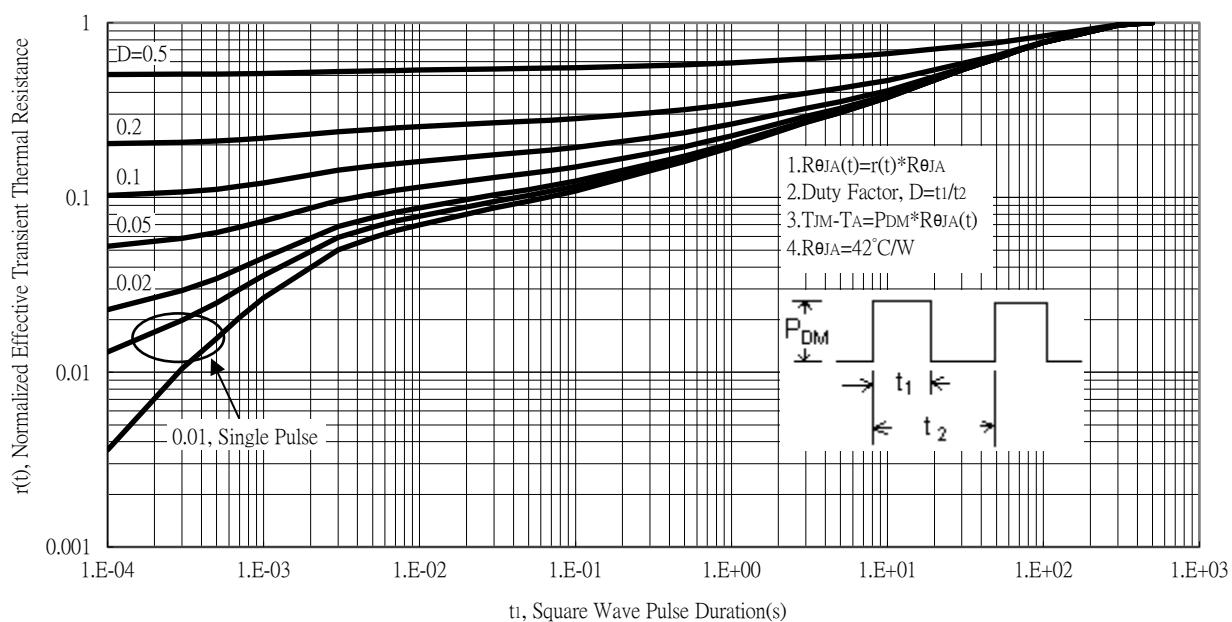


Typical Characteristics (Cont.)

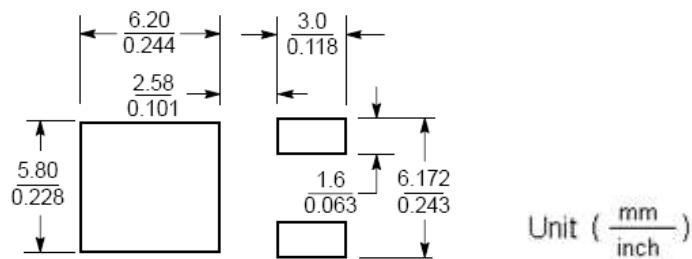
Single Pulse Power Rating, Junction to Ambient



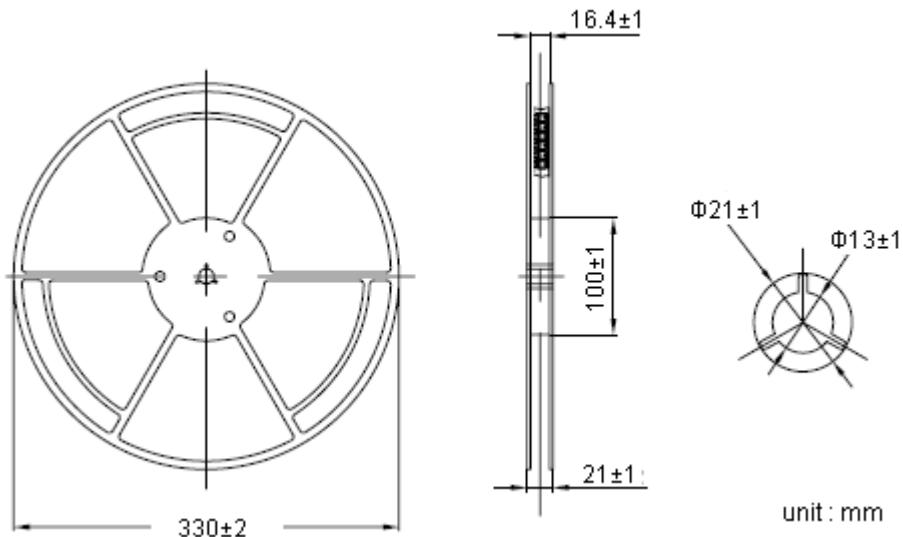
Transient Thermal Response Curves



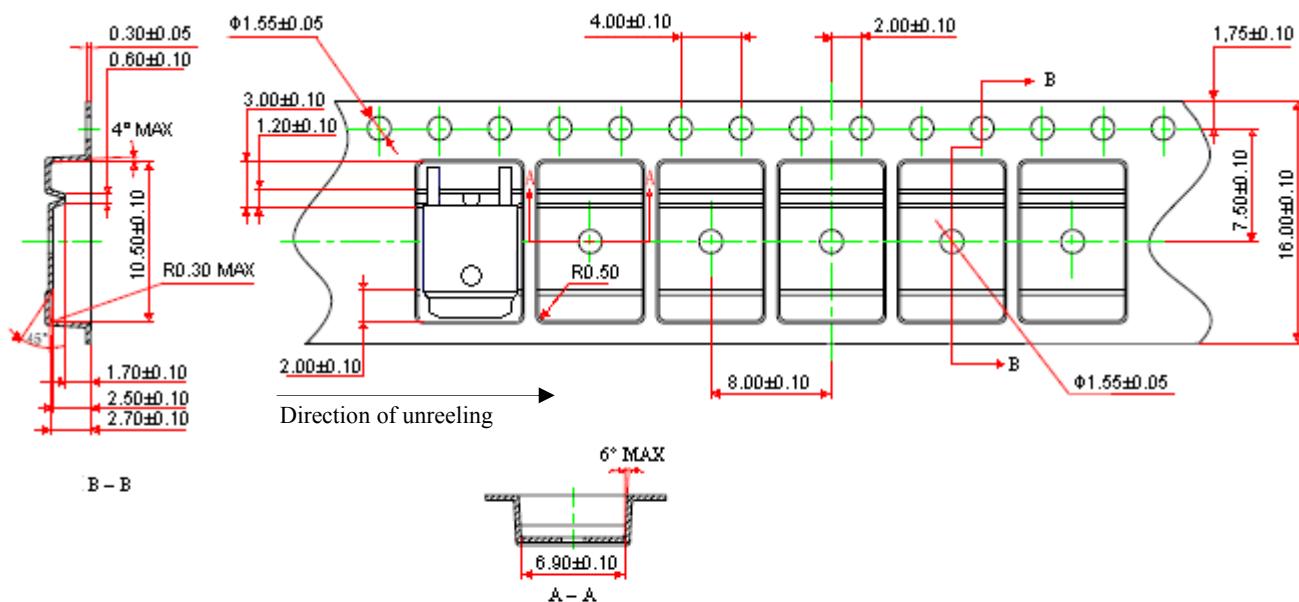
Recommended soldering footprint



Reel Dimension



Carrier Tape Dimension

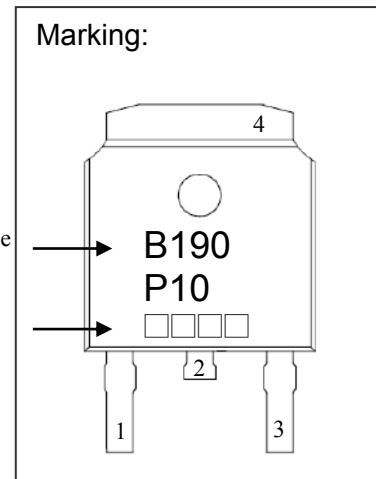
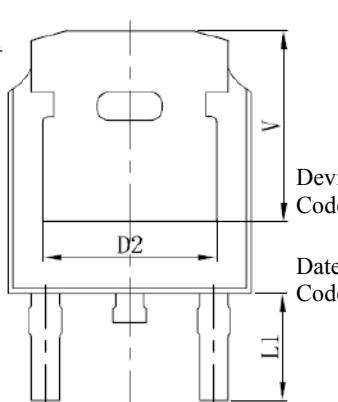
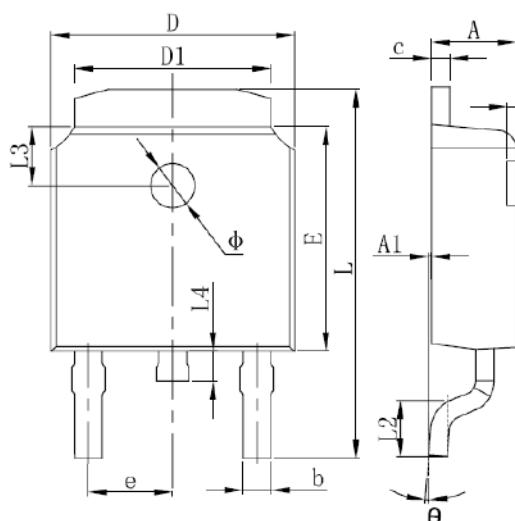


Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2 .
2. Camber not to exceed 1mm in 100mm.
3. Material: conductive black polystyrene, antistatic coated : $10^5 \Omega/\square \sim 10^{11} \Omega/\square$

unit : mm

TO-252 Dimension



Style: Pin 1.Gate 2.Drain 3.Source
4.Drain

3-Lead TO-252 Plastic Surface Mount Package

Date Code(counting from left to right) :

1st code: year code, the last digit of Christian year

2nd code : month code, Jan→A, Feb→B, Mar→C,

Apr→D, May→E, Jun→F, Jul→G, Aug→H,

Sep→J, Oct→K, Nov→L, Dec→M

3rd and 4th codes : production serial number, 01~99

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.087	0.094	2.200	2.400	L	0.382	0.406	9.712	10.312
A1	0.000	0.005	0.000	0.127	L1	0.114	REF	2.900	REF
b	0.025	0.030	0.635	0.770	L2	0.055	0.067	1.400	1.700
c	0.018	0.023	0.460	0.580	L3	0.063	REF	1.600	REF
D	0.256	0.264	6.500	6.700	L4	0.024	0.039	0.600	1.000
D1	0.201	0.215	5.100	5.460	Φ	0.043	0.051	1.100	1.300
D2	0.190	REF	4.830	REF	θ	0°	8°	0°	8°
E	0.236	0.244	6.000	6.200	h	0.000	0.012	0.000	0.300
e	0.086	0.094	2.186	2.386	V	0.207	REF	5.250	REF